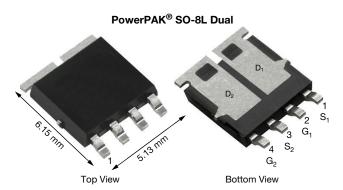
Vishay Siliconix

Automotive Dual N-Channel 40 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY				
V _{DS} (V)	40			
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.0093			
$R_{DS(on)}(\Omega)$ at $V_{GS} = 4.5 \text{ V}$	0.0111			
I _D (A) per leg	30			
Configuration	Dual			

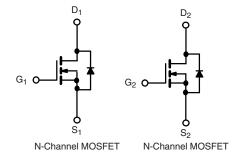
FEATURES

- TrenchFET® power MOSFET
- 100 % R_g and UIS tested
- AEC-Q101 qualified d
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





ROHS COMPLIANT HALOGEN FREE



ORDERING INFORMATION	
Package	PowerPak SO-8L
Lead (Pb)-free and halogen-free	SQJ912AEP (for detailed order number please see www.vishay.com/doc?79771)

ABSOLUTE MAXIMUM RATINGS	(T _C = 25 °C, unles	ss otherwise noted			
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V_{DS}	40	V	
Gate-source voltage		V_{GS}	± 20	V	
Continuous drain current ^a	T _C = 25 °C	I-	30		
Continuous drain current	T _C = 125 °C	l _D	29		
Continuous source current (diode conduction) a		I _S	30	А	
Pulsed drain current ^b		I _{DM}	120		
Single pulse avalanche current L = 0.1 mH		I _{AS}	26		
Single pulse avalanche energy	L = 0.1 IIII	E _{AS}	34	mJ	
Maximum power dissipation ^b	T _C = 25 °C	P _D	48	W	
Maximum power dissipation -	T _C = 125 °C	ГD	16	VV	
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C	
Soldering recommendations (peak temperature) e, f			260	C	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient F	PCB mount c	R_{thJA}	85	°C/W
Junction-to-case (drain)		R_{thJC}	3.1	C/VV

Notes

- a. Package limited
- b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %
- c. When mounted on 1" square PCB (FR4 material)
- d. Parametric verification ongoing
- a. See solder profile (<u>www.vishay.com/doc?73257</u>). The PowerPAK SO-8L is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- f. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components



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PARAMETER	SYMBOL	TES	MIN.	TYP.	MAX.	UNIT	
Static				l	•		ı
Drain-source breakdown voltage	V _{DS}	V _{GS} :	= 0 V, I _D = 250 μA	40	-	-	.,
Gate-source threshold voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$		1.5	2	2.5	V
Gate-source leakage	I _{GSS}	V _{DS} =	0 V, V _{GS} = ± 20 V	-	-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = 40 V	-	-	1	
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 40 V, T _J = 125 °C	-	-	50	μΑ
-		$V_{GS} = 0 V$	V _{DS} = 40 V, T _J = 175 °C	-	-	150	1
On-state drain current a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 \text{ V}$	30	-	-	Α
		V _{GS} = 10 V	I _D = 9.7 A	-	0.0077	0.0093	Ω
During	_	V _{GS} = 4.5 V	I _D = 8.9 A	-	0.0093	0.0111	
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 9.7 A, T _J = 125 °C	-	-	0.0138	
		V _{GS} = 10 V	I _D = 9.7 A, T _J = 175 °C	-	-	0.0169	
Forward transconductance b	9 _{fs}	V_{DS}	= 15 V, I _D = 10 A	-	58	-	S
Dynamic ^b							
Input capacitance	C _{iss}			-	1438	1835	
Output capacitance	C _{oss}	$V_{GS} = 0 V$	$V_{DS} = 20 \text{ V}, f = 1 \text{ MHz}$	-	217	271	pF
Reverse transfer capacitance	C _{rss}			-	91	114	
Total gate charge ^c	Q_g			-	25.6	38	
Gate-source charge c	Q_{gs}	V _{GS} = 10 V	$V_{DS} = 20 \text{ V}, I_{D} = 11.3 \text{ A}$	-	4	-	nC
Gate-drain charge c	Q _{gd}			-	4	-	
Gate resistance	R _g		f = 1 MHz	0.72	1.44	2.2	Ω
Turn-on delay time ^c	t _{d(on)}			-	10	15	
Rise time ^c	t _r	V _{DD} :	= 20 V, $R_1 = 20 \Omega$	-	9	14	
Turn-off delay time ^c	t _{d(off)}	$I_D \cong 1 \text{ A}, Y$	$V_{GEN} = 10 \text{ V}, R_g = 1 \Omega$	-	23	35	ns
Fall time ^c	t _f	1		-	11	17	
Source-Drain Diode Ratings and Char	acteristics ^b				•		
Pulsed current ^a	I _{SM}			-	-	120	Α
Forward voltage	V_{SD}	I _F = 6.5 A, V _{GS} = 0 V		_	0.8	1.1	V

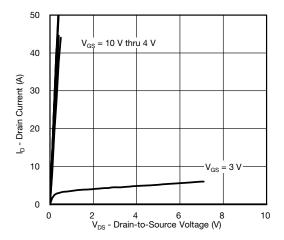
Notes

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

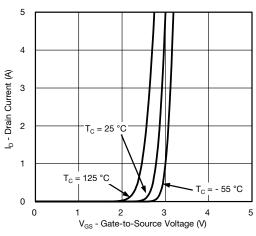
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



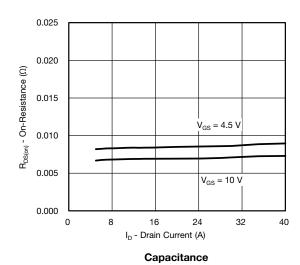
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

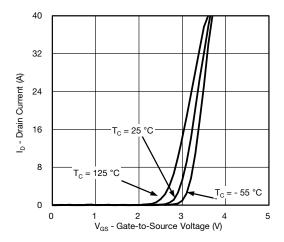


Output Characteristics

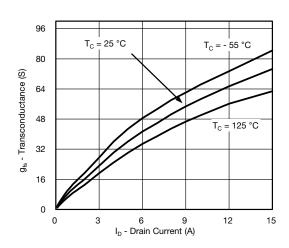


Transfer Characteristics

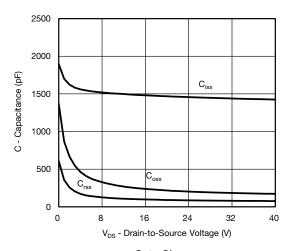




Transfer Characteristics



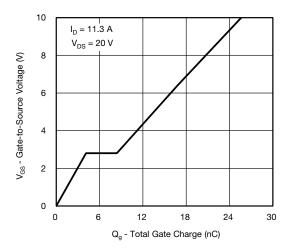
Transconductance



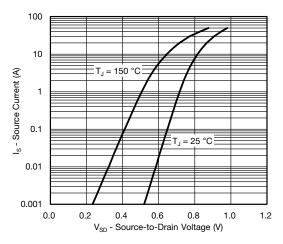
Gate Charge



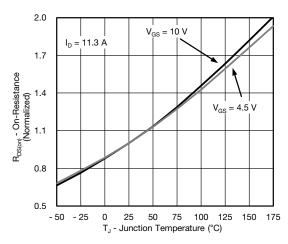
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



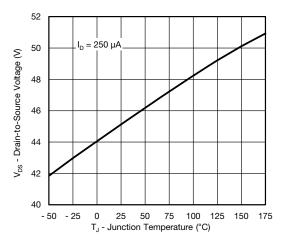
Gate Charge



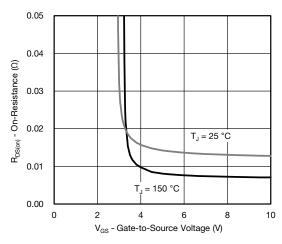
Source Drain Diode Forward Voltage



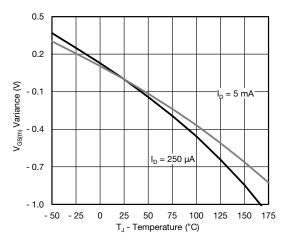
On-Resistance vs. Junction Temperature



Drain-Source Breakdown vs. Junction Temperature



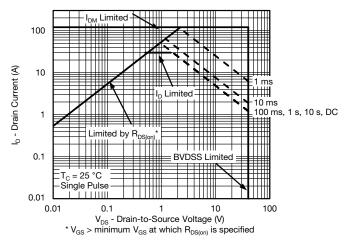
On-Resistance vs. Gate-to-Source Voltage



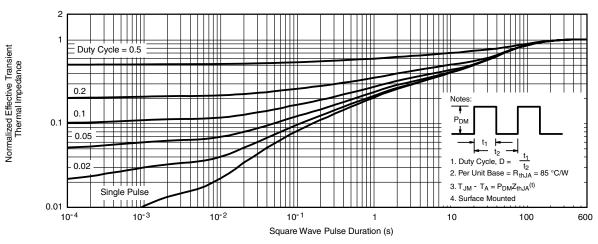
Threshold Voltage



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



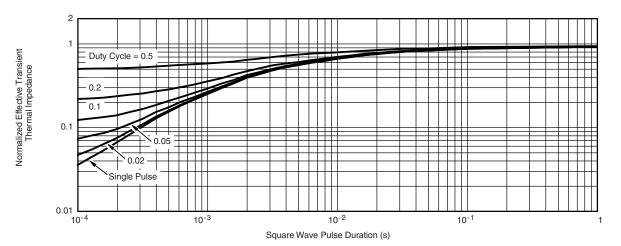
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

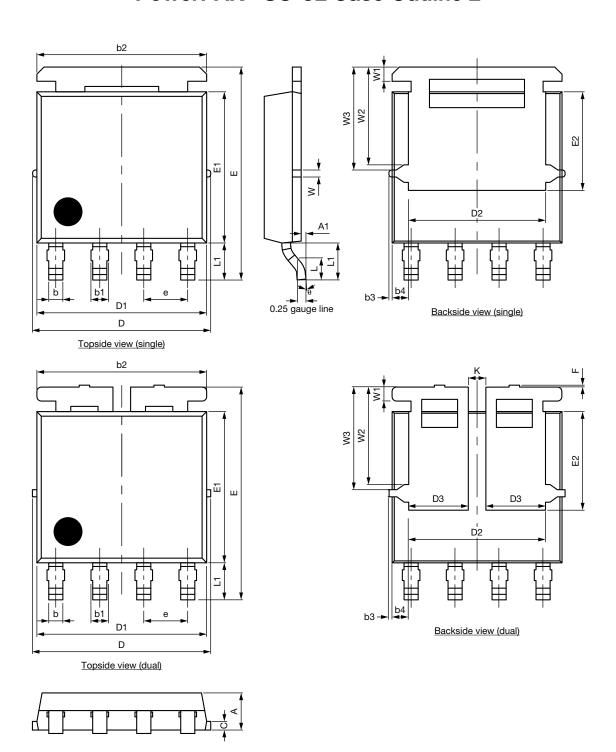
Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C) are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg262876.



PowerPAK® SO-8L Case Outline 2





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DIM		MILLIMETERS			INCHES			
DIM.	MIN.	NOM.	M. MAX. MIN. NOM.		MIN. NOM.		NOM. MAX	
Α	1.00	1.07	1.14	0.039	0.042	0.045		
A1	0.00	-	0.127	0.00	-	0.005		
b	0.33	0.41	0.48	0.013	0.016	0.019		
b1	0.44	0.51	0.58	0.017	0.020	0.023		
b2	4.80	4.90	5.00	0.189	0.193	0.197		
b3		0.094			0.004			
b4		0.47			0.019			
С	0.20	0.25	0.30	0.008	0.010	0.012		
D	5.00	5.13	5.25	0.197	0.202	0.207		
D1	4.80	4.90	5.00	0.189	0.193	0.197		
D2	3.86	3.96	4.06	0.152	0.156	0.160		
D3	1.63	1.73	1.83	0.064	0.068	0.072		
е		1.27 BSC		0.050 BSC				
Е	6.05	6.15	6.25	0.238	0.242	0.246		
E1	4.27	4.37	4.47	0.168	0.172	0.176		
E2	2.75	2.85	2.95	0.108	0.112	0.116		
F	-	-	0.15	-	-	0.006		
L	0.62	0.72	0.82	0.024	0.028	0.032		
L1	0.92	1.07	1.22	0.036	0.042	0.048		
K		0.51			0.020			
W	0.23		0.009					
W1		0.41		0.016				
W2		2.82		0.111				
W3	2.96			0.117				
θ	0°	-	10°	0°	-	10°		

ECN: C21-1498-Rev. C, 01-Nov-2021

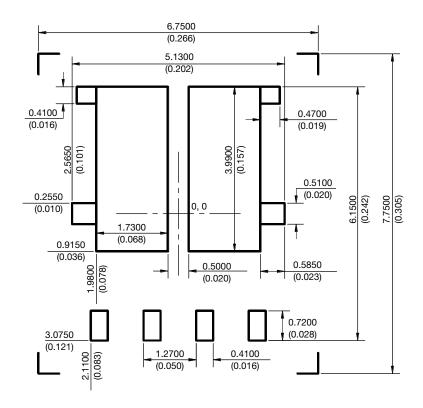
DWG: 6044

Note

• Millimeters will govern



RECOMMENDED MINIMUM PAD FOR PowerPAK® SO-8L DUAL



Recommended Minimum Pads Dimensions in mm (inches) Keep-out 6.75 (0.266) x 7.75 (0.305)



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